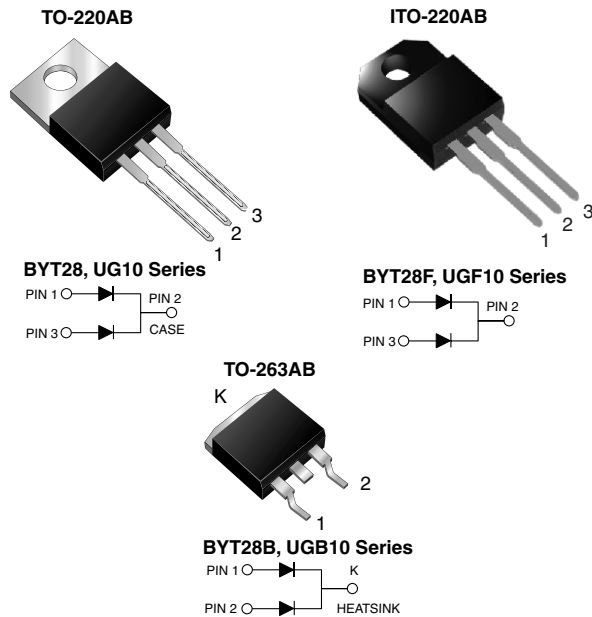


## Dual Common-Cathode Ultrafast Soft Recovery Rectifier



### FEATURES

- Glass passivated chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Meets MSL level 1, per J-STD-020C, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, dc-to-dc converters, and other power switching application.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	5 A x 2
$V_{RRM}$	300 V, 400 V
$I_{FSM}$	60 A
$t_{rr}$	35 ns
$V_F$	1.05 V
$T_J \text{ max.}$	150 °C

MAXIMUM RATINGS ( $T_C = 25 \text{ }^\circ\text{C}$ unless otherwise noted)				
PARAMETER	SYMBOL	BYT28-300 UG10FCT	BYT28-400 UG10GCT	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	300	400	V
Maximum working reverse voltage	$V_{RWM}$	300	400	V
Maximum RMS voltage	$V_{RMS}$	210	280	
Maximum DC blocking voltage	$V_{DC}$	300	400	V
Maximum average forward rectified current at $T_C = 100 \text{ }^\circ\text{C}$ total device per diode	$I_{F(AV)}$	10 5.0		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	60		A
Operating junction and storage temperature range	$T_J, T_{STG}$	- 40 to + 150		°C
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1 \text{ min}$	$V_{AC}$	1500		V



<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	$I_F = 5\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$	$V_F$	1.30	V
	$I_F = 10\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$		1.40	
	$I_F = 5\text{ A}$	$T_J = 150\text{ }^\circ\text{C}$		1.05	
Maximum reverse current per diode at $V_{RRM}$		$T_J = 25\text{ }^\circ\text{C}$ $T_J = 100\text{ }^\circ\text{C}$	$I_R$	10 200	$\mu\text{A}$
Maximum reverse recovery time per diode	$I_F = 0.5\text{ A}$ , $I_R = 1.0\text{ A}$ , $I_{rr} = 0.25\text{ A}$		$t_{rr}$	35	ns
Maximum reverse recovery time per diode	$I_F = 1.0\text{ A}$ , $dI/dt = 100\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ , $I_{rr} = 0.1 I_{RM}$		$t_{rr}$	50	ns
Maximum reverse recovery current per diode	$I_F = 5\text{ A}$ , $dI/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ , $T_C = 100\text{ }^\circ\text{C}$		$I_{RM}$	3.0	A
Maximum stored charge per diode	$I_F = 2\text{ A}$ , $dI/dt = 20\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ , $I_{rr} = 0.1 I_{RM}$		$Q_{rr}$	50	nC

**Note:**

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	BYT28 UG10	BYT28F UGF10	BYT28B UGB10	UNIT
Typical thermal resistance junction to case per diode	$R_{\theta JC}$	4.5	6.7	4.5	$^\circ\text{C}/\text{W}$

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	BYT28-400-E3/45	1.80	45	50/tube	Tube
ITO-220AB	BYT28F-400-E3/45	1.95	45	50/tube	Tube
TO-263AB	BYT28B-400-E3/45	1.77	45	50/tube	Tube
TO-263AB	BYT28B-400-E3/81	1.77	81	800/reel	Tape reel
TO-220AB	BYT28-400HE3/45 <sup>(1)</sup>	1.80	45	50/tube	Tube
ITO-220AB	BYT28F-400HE3/45 <sup>(1)</sup>	1.95	45	50/tube	Tube
TO-263AB	BYT28B-400HE3/45 <sup>(1)</sup>	1.77	45	50/tube	Tube
TO-263AB	BYT28B-400HE3/81 <sup>(1)</sup>	1.77	81	800/reel	Tape reel

**Note:**

(1) Automotive grade AEC Q101 qualified



**RATINGS AND CHARACTERISTICS CURVES**

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

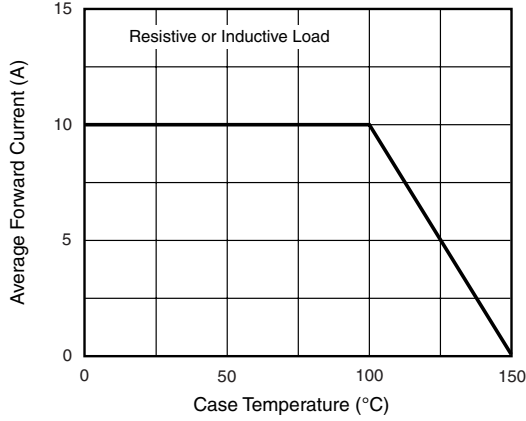


Figure 1. Forward Current Derating Curve

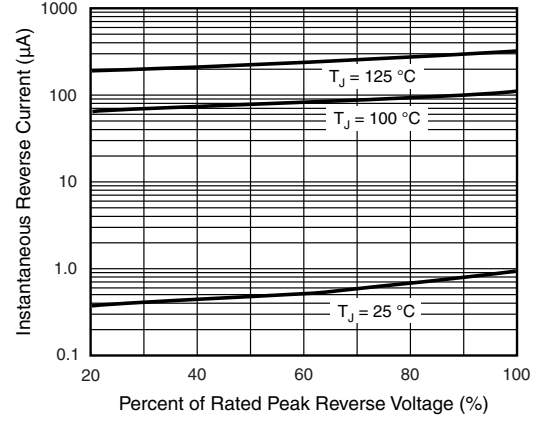


Figure 4. Typical Reverse Characteristics Per Diode

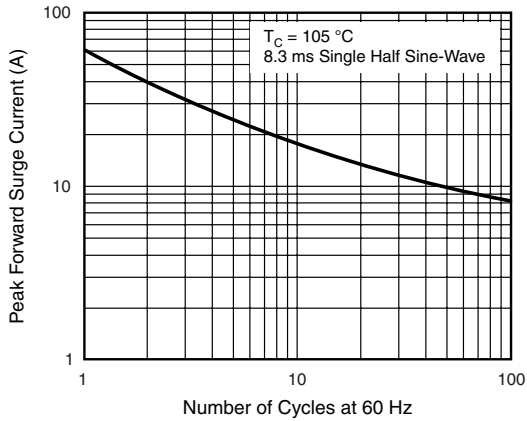


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

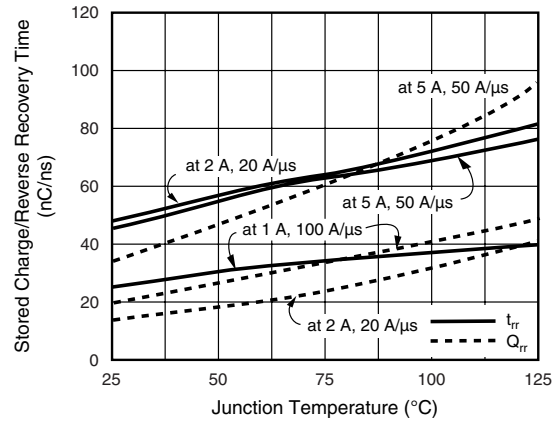


Figure 5. Reverse Switching Characteristics Per Diode

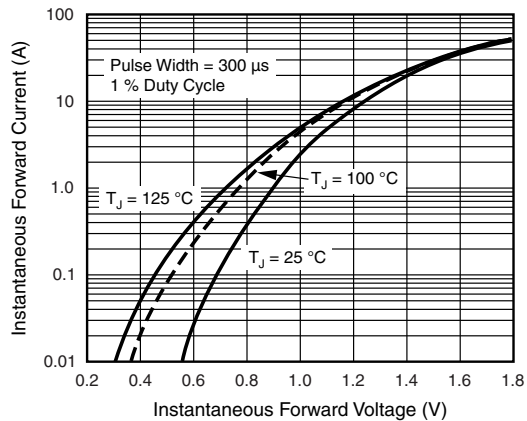


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

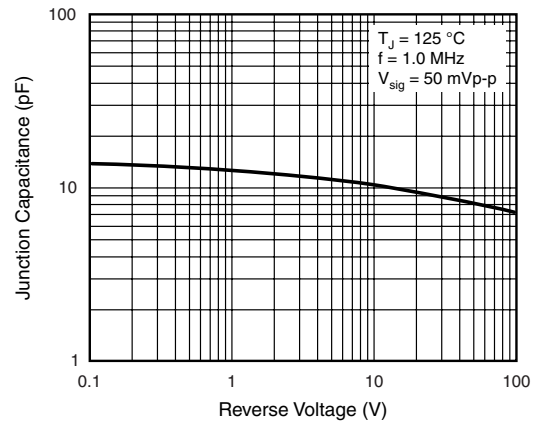
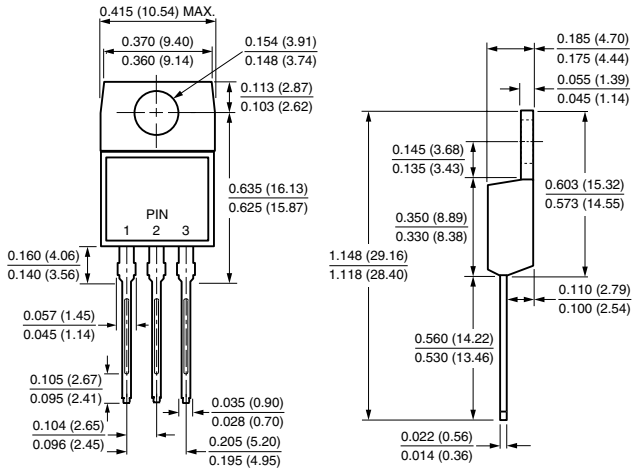


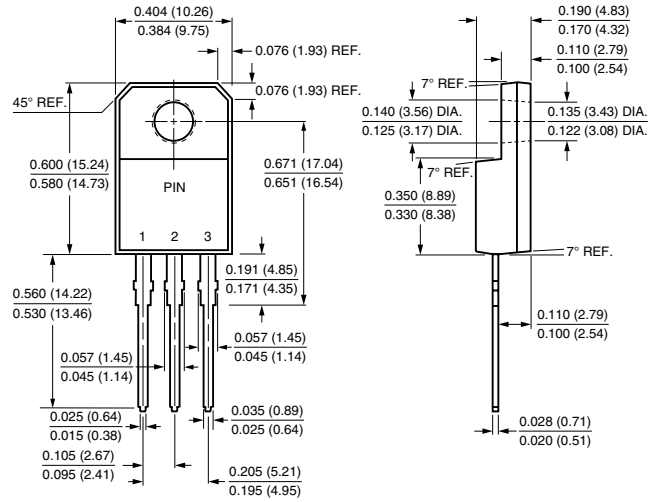
Figure 6. Typical Junction Capacitance Per Diode

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

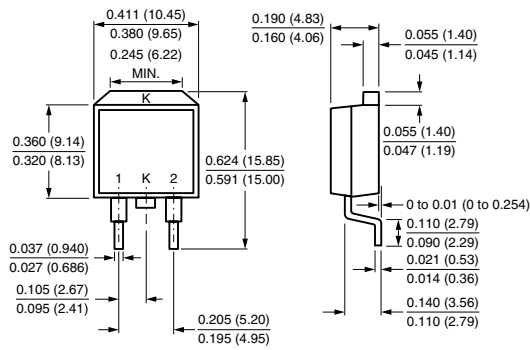
**TO-220AB**



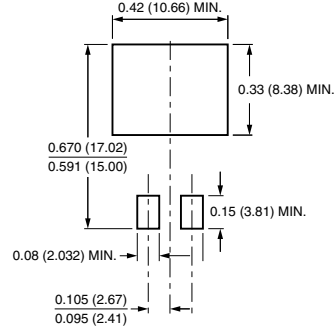
**ITO-220AB**



**TO-263AB**



**Mounting Pad Layout**





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